

Features

- Fast average current control
- Programmable constant off-time switching
- Linear dimming input
- PWM dimming input
- Output short circuit protection with skip mode
- Ambient operating temperature -40°C to +125°C
- Pin-compatible with the LD7101

Applications

- DC/DC or AC/DC LED driver applications
- RGB backlighting LED driver
- Backlighting of flat panel displays
- General-purpose constant current source
- Signage and decorative LED lighting
- Automotive
- Chargers

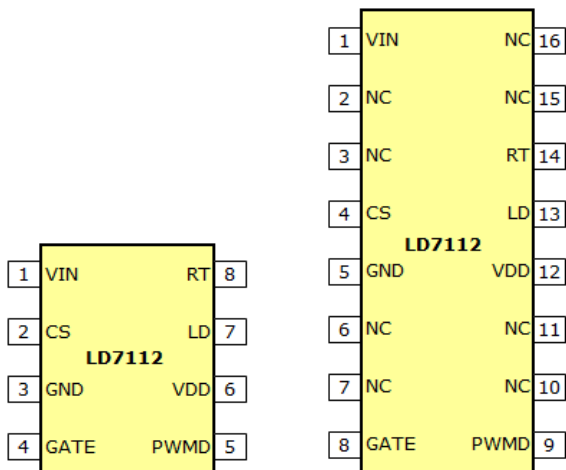
General Description

The LD7112 is an average current mode control LED driver IC operating in a constant off-time mode. Unlike LD7101, this control IC does not produce a peak-to-average error, and therefore greatly improves accuracy, line and load regulation of the LED current without any need for loop compensation or high-side current sensing. The output LED current accuracy is $\pm 3\%$.

The IC is equipped with a current limit comparator for hiccup-mode output short circuit protection.

The LD7112 can be powered from 8V to 450V supply. A PWM dimming input is provided that accepts an external control TTL compatible signal. The output current can be programmed by an internal 275mV reference, or controlled externally through a 0~1.5V dimming input.

Package Pin Out

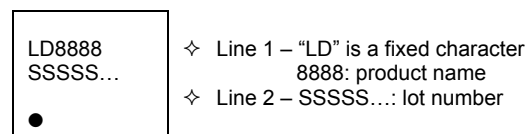


Ordering Information

Part No.	Package	Packing Options	
		Tube (TU)	Tape & Reel (TR)
LD7112	SOP-8	LD7112S1-TU	LD7112S1-TR
	SOP-16	LD7112S3-TU	LD7112S3-TR

- Package material default is "Green" package.

Product Marking



Absolute Maximum Ratings

Parameter	Maximum	Unit
V _{IN} to GND	-0.5 to +500	V
V _{DD} to GND	12	V
CS, LD, PWM, GATE, RT to GND	-0.3 to V _{DD} +0.3	V
Power dissipation T _A = +25°C SOP-8	650	mW
Power dissipation T _A = +25°C SOP-16	1100	mW
Operating temperature range	-40 to +125	°C
Junction temperature range	-45 to +150	°C
Storage temperature range	-65 to +150	°C

The values beyond the boundaries of absolute maximum rating may cause the damage to the device. Functional operation in this context is not implied. Continuous use of the device at the absolute rating level might influence device reliability. All voltages have their reference to device ground.

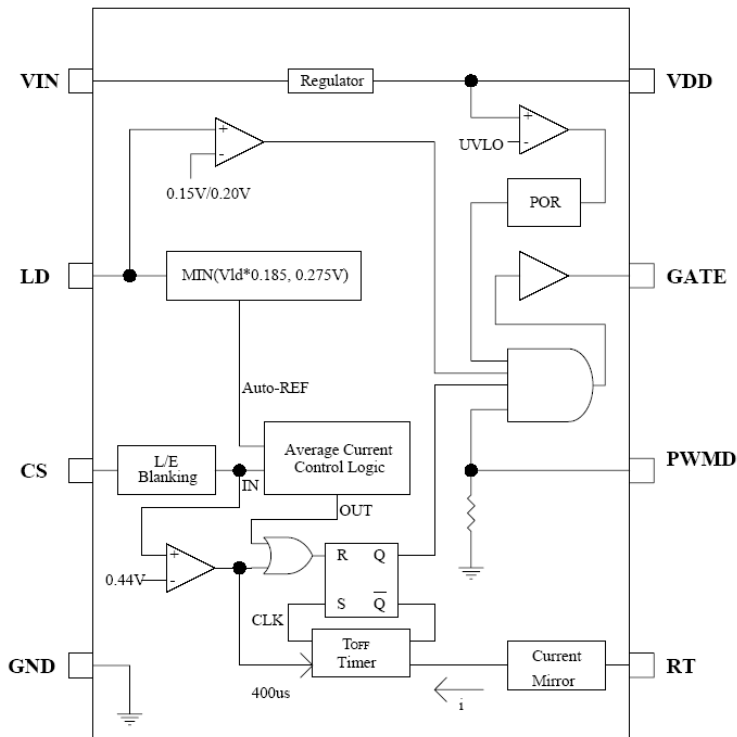
Electrical Characteristics

V_{IN}=12V, V_{LD}=V_{DD}, V_{PWM}=V_{DD}, T_A=25°C unless specified, otherwise values are guaranteed by production testing requirements.

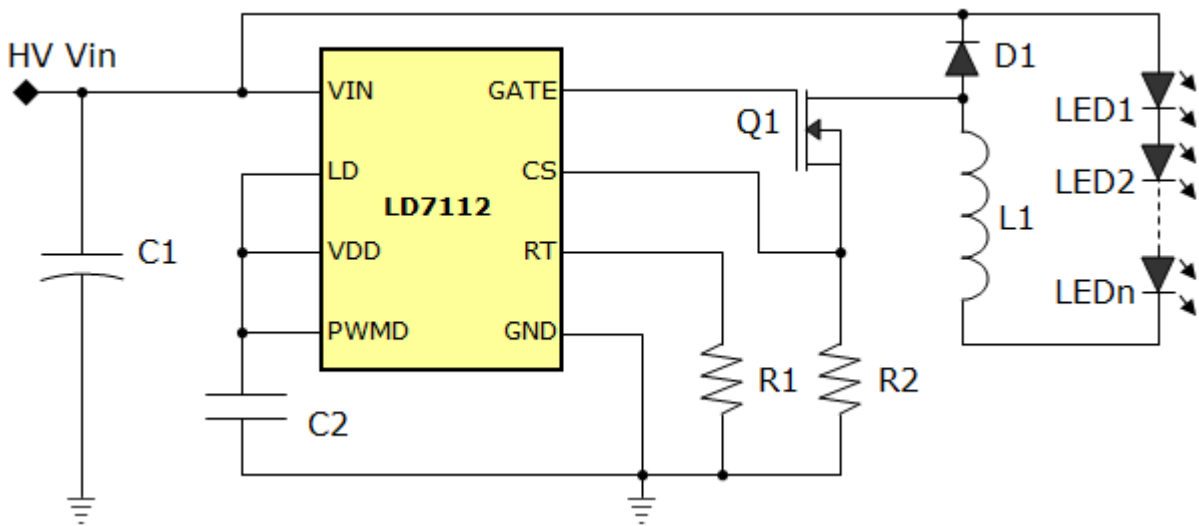
Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Input						
Input DC supply voltage range ²	V _{INDC}	DC input voltage	8.0	–	450	V
Shut-down mode supply current ²	I _{INSD}	Pin PWM to GND	–	0.5	1.0	mA
Internal Regulator						
Internally regulated voltage ¹	V _{DD}	V _{IN} = 8V, I _{DD(ext)} =0	7.25	7.5	7.75	V
Line regulation of V _{DD} ¹	ΔV _{DDLINE}	I _{DDEXT} = 8 to 450V	0	–	1.0	V
Load regulation of V _{DD} ¹	ΔV _{DDLLOAD}	I _{DDEXT} = 0 to 1.0mA	0	–	100	mV
V _{DD} under voltage lockout threshold ²	UVLO	V _{IN} rising	6.45	6.7	6.95	mV
V _{DD} under voltage lockout hysteresis	ΔUVLO	V _{IN} falling	–	500	–	mV
Maximum input current ¹	I _{INMAX}	V _{IN} = 8V	3.5	–	–	mA
		V _{IN} = 8V, limited by UVLO	1.5	–	–	
PWM Dimming						
Pin PWM input low voltage ²	V _{EN(lo)}	V _{IN} = 8 to 450V	–	–	0.8	V
Pin PWM input high voltage ²	V _{EN(hi)}	V _{IN} = 8 to 450V	2.2	–	–	V
Pin PWM pull-down resistance	R _{EN}	V _{PWM} = 5V	50	100	150	KΩ
Average Current Sense Logic						
Current sense reference voltage	V _{CS}	–	268	–	286	mV
LD to CS voltage ratio	A _{LD}	–	0.182	–	0.188	–
LD to CS voltage offset	V _{OFST}	V _{OFST} = V _{CS} - A _{LD} * V _{LD} , V _{LD} = 1.2V	0	–	10	mV
CS threshold temperature regulation ²	ΔV _{CS}	–	0	–	5.0	mV
LD shutdown input voltage	V _{LDSDN}	V _{LD} falling	–	150	–	mV
LD enable input voltage	V _{LDENB}	V _{LD} rising	–	200	–	mV
Current sense blanking interval ²	T _{BLANK}	–	150	–	320	nS
Minimum on-time	T _{ONMIN}	CS = V _{CS} + 30mV	–	–	1000	nS
Maximum steady state duty cycle	D _{MAX}	Current reduced may occur if beyond	75	–	–	%
Short Circuit Protection						
HICCUP threshold voltage	V _{CSSTH}	–	410	–	470	mV
Current limit delay CS to GATE	T _{DELAY}	CS = V _{CS} + 30mV	–	–	150	nS
Short circuit HICCUP time	T _{HICCUP}	–	350	–	550	μS
Minimum on-time (short circuit)	T _{ONMINS}	CS = V _{DD}	–	–	430	nS
T_{OFF} Timer						
Off time	T _{OFF}	R _T = 1.00MΩ	32	40	48	μS
		R _T = 226KΩ	8.0	10	12	
GATE Driver						
GATE sourcing current	I _{SOURCE}	V _{GATE} = 0V, V _{DD} = 7.5V	0.165	–	–	A
GATE sinking current	I _{SINK}	V _{GATE} = V _{DD} , V _{DD} = 7.5V	0.165	–	–	A
GATE output rise time	T _{RISE}	C _{GATE} = 500pF, V _{DD} = 7.5V	–	30	50	nS
GATE output fall time	T _{FALL}	C _{GATE} = 500pF, V _{DD} = 7.5V	–	30	50	nS

Note: 1. 500pF at GATE; R_T = 226KΩ, PWM = V_{DD}. 2. Denotes the specifications which apply over the full operating ambient temperature range of -40°C < T_A < +125°C. 3. Guaranteed by design.

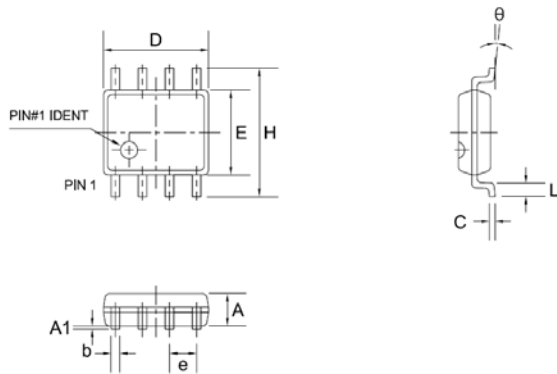
Block Diagram



Typical Application Circuit

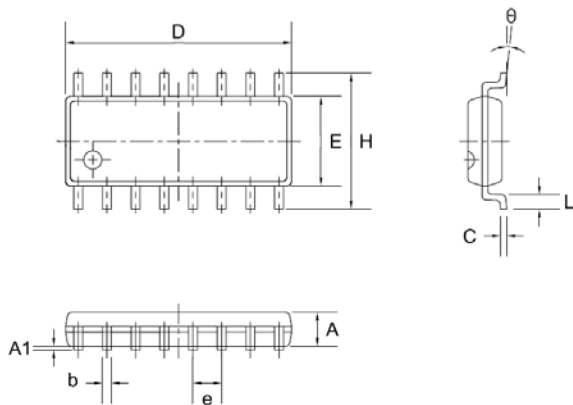


Package Outline
SOP8:



Symbol	Dimensions In Millimeters			Dimensions In Inches		
	Min	Nom	Max	Min	Nom	Max
A	—	—	4.31	—	—	0.170
A1	0.38	—	—	0.015	—	—
A2	3.15	3.40	3.65	0.124	0.134	0.144
B	—	0.46	—	—	0.018	—
B1	—	1.52	—	—	0.060	—
C	—	0.25	—	—	0.010	—
D	9.00	9.20	9.40	0.354	0.362	0.370
E	6.20	6.40	6.60	0.244	0.252	0.260
E1	—	7.62	—	—	0.300	—
e	—	2.54	—	—	0.100	—
L	3.00	3.30	3.60	0.118	0.130	0.142
θ	0°	—	15°	0°	—	15°

SOP-16:



Symbol	Dimensions In Millimeters			Dimensions In Inches		
	Min	Nom	Max	Min	Nom	Max
A	1.30	1.50	1.70	0.051	0.059	0.067
A1	0.06	0.16	0.26	0.002	0.006	0.010
b	0.30	0.40	0.55	0.012	0.016	0.022
C	0.15	0.25	0.35	0.006	0.010	0.014
D	9.70	10.00	10.30	0.382	0.394	0.406
E	3.75	3.95	4.15	0.148	0.156	0.163
e	1.15	1.27	1.39	0.045	0.050	0.055
H	5.70	6.00	6.30	0.224	0.236	0.248
L	0.45	0.65	0.85	0.018	0.026	0.033
θ	0°	—	8°	0°	—	8°

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